

PE3336

Product Description

Peregrine's PE3336 is a high performance integer-N PLL capable of frequency synthesis up to 3.0 GHz. The superior phase noise performance of the PE3336 makes it ideal for applications such as LMDS / MMDS / WLL basestations and demanding terrestrial systems.

The PE3336 features a 10/11 dual modulus prescaler, counters and a phase comparator as shown in Figure 1. Counter values are programmable through either a serial or parallel interface and can also be directly hard wired.

The PE3336 is optimized for terrestrial applications. Fabricated in Peregrine's patented UTSi® (Ultra Thin Silicon) CMOS technology, the PE3336 offers excellent RF performance with the economy and integration of conventional CMOS.

3.0 GHz Integer-N PLL for Low Phase Noise Applications

Features

- 3.0 GHz operation
- ÷10/11 dual modulus prescaler
- Internal phase detector
- Serial, parallel or hardwired programmable
- Pin compatible with PE3236
- Available in 44-lead PLCC and miniature 48-lead MLP package
- Ultra-low phase noise

Figure 1. Block Diagram

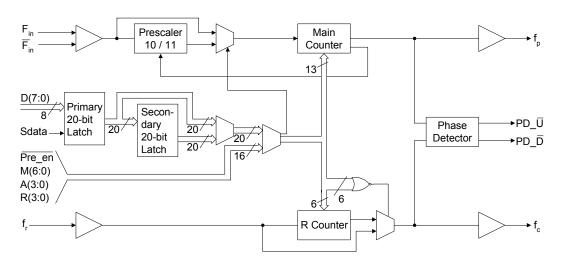




Figure 2. Pin Configuration

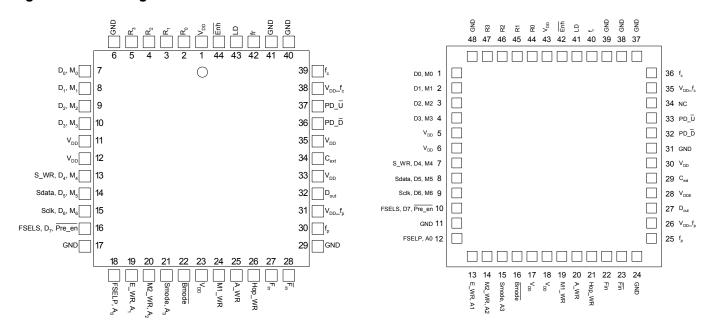


Table 1. Pin Descriptions

44-lead PLCC

Pin No. (44-lead PLCC)	Pin No. (48-lead MLPQ)	Pin Name	Interface Mode	Туре	Description
1	43	V_{DD}	ALL	(Note 1)	Power supply input. Input may range from 2.85 V to 3.15 V. Bypassing recommended.
2	44	R ₀	Direct	Input	R Counter bit0 (LSB).
3	45	R ₁	Direct	Input	R Counter bit1.
4	46	R ₂	Direct	Input	R Counter bit2.
5	47	R ₃	Direct	Input	R Counter bit3.
6	48	GND	ALL	(Note 1)	Ground.
7	1	D ₀	Parallel	Input	Parallel data bus bit0 (LSB).
,	-	M ₀	Direct	Input	M Counter bit0 (LSB).
8	2	D ₁	Parallel	Input	Parallel data bus bit1.
0	2	M ₁	Direct	Input	M Counter bit1.
9	3	D ₂	Parallel	Input	Parallel data bus bit2.
9	3	M ₂	Direct	Input	M Counter bit2.
10	4	D ₃	Parallel	Input	Parallel data bus bit3.
10	4	M ₃	Direct	Input	M Counter bit3.
11	5	V _{DD}	ALL	(Note 1)	Same as pin 1.
12	6	V _{DD}	ALL	(Note 1)	Same as pin 1.

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48-lead MLPQ



Pin No. (44-lead PLCC)	Pin No. (48-lead MLPQ)	Pin Name	Interface Mode	Туре	Description
13	7	S_WR	Serial	Input	Serial load enable input. While S_WR is "low", Sdata can be serially clocked. Primary register data are transferred to the secondary register on S_WR or Hop_WR rising edge.
		D ₄	Parallel	Input	Parallel data bus bit4
		M ₄	Direct	Input	M Counter bit4
		Sdata	Serial	Input	Binary serial data input. Input data entered MSB first.
14	8	D ₅	Parallel	Input	Parallel data bus bit5.
		M ₅	Direct	Input	M Counter bit5.
15	9	Sclk	Serial	Input	Serial clock input. Sdata is clocked serially into the 20-bit primary register (E_WR "low") or the 8-bit enhancement register (E_WR "high") on the rising edge of Sclk.
.0	Ü	D ₆	Parallel	Input	Parallel data bus bit6.
		M ₆	Direct	Input	M Counter bit6.
		FSELS	Serial	Input	Selects contents of primary register (FSELS=1) or secondary register (FSELS=0) for programming of internal counters while in Serial Interface Mode.
16	10	D ₇	Parallel	Input	Parallel data bus bit7 (MSB).
		Pre_en	Direct	Input	Prescaler enable, active "low". When "high", F _{in} bypasses the prescaler.
17	11	GND	ALL		Ground.
18	12	FSELP	Parallel	Input	Selects contents of primary register (FSELP=1) or secondary register (FSELP=0) for programming of internal counters while in Parallel Interface Mode.
		A ₀	Direct	Input	A Counter bit0 (LSB).
		E_WR	Serial	Input	Enhancement register write enable. While E_WR is "high", Sdata can be serially clocked into the enhancement register on the rising edge of Sclk.
19	13	L_VVIX	Parallel	Input	Enhancement register write. D[7:0] are latched into the enhancement register on the rising edge of E_WR.
		A ₁	Direct	Input	A Counter bit1.
20	14	M2_WR	Parallel	Input	M2 write. D[3:0] are latched into the primary register (R[5:4], M[8:7]) on the rising edge of M2_WR.
		A ₂	Direct	Input	A Counter bit2.
21	15	Smode	Serial, Parallel	Input	Selects serial bus interface mode (Bmode=0, Smode=1) or Parallel Interface Mode (Bmode=0, Smode=0).
		A ₃	Direct	Input	A Counter bit3 (MSB).
22	16	Bmode	ALL	Input	Selects direct interface mode (Bmode=1).
23	17,18	V _{DD}	ALL	(Note 1)	Same as pin 1.
24	19	M1_WR	Parallel	Input	M1 write. D[7:0] are latched into the primary register (Pre_en, M[6:0]) on the rising edge of M1_WR.
25	20	A_WR	Parallel	Input	A write. D[7:0] are latched into the primary register (R[3:0], A[3:0]) on the rising edge of A_WR.
26	21	Hop_WR	Serial, Parallel	Input	Hop write. The contents of the primary register are latched into the secondary register on the rising edge of Hop_WR.
27	22	Fin	ALL	Input	Prescaler input from the VCO. 3.0 GHz max frequency.



Pin No. (44-lead PLCC)	Pin No. (48-lead MLPQ)	Pin Name	Interface Mode	Туре	Description
28	23	Fin	ALL	Input	Prescaler complementary input. A bypass capacitor should be placed as close as possible to this pin and be connected in series with a 50 Ω resistor directly to the ground plane.
29	24	GND	ALL		Ground.
30	25	f _p	ALL	Output	Monitor pin for main divider output. Switching activity can be disabled through enhancement register programming or by floating or grounding V _{DD} pin 31.
31	26	V_{DD} - f_p	ALL	(Note 1)	V_{DD} for $f_p.$ Can be left floating or connected to GND to disable the f_p output.
32	27	Dout	Serial, Parallel	Output	Data Out. The MSEL signal and the raw prescaler output are available on Dout through enhancement register programming.
33	28	V_{DD}	ALL	(Note 1)	Same as pin 1.
34	29	Cext	ALL	Output	Logical "NAND" of PD_ \overline{U} and PD_ \overline{D} terminated through an on chip, 2 k Ω series resistor. Connecting Cext to an external capacitor will low pass filter the input to the inverting amplifier used for driving LD.
35	30	V_{DD}	ALL	(Note 1)	Same as pin 1.
36	32	PD_D	ALL	Output	$PD_\overline{D}$ is pulse down when f_p leads f_c .
37	33	PD_Ū	ALL		$PD_\overline{U}$ is pulse down when f_c leads f_p .
38	35	V _{DD} -f _c	ALL	(Note 1)	V_{DD} for f_{c} can be left floating or connected to GND to disable the f_{c} output.
39	36	f _c	ALL	Output	Monitor pin for reference divider output. Switching activity can be disabled through enhancement register programming or by floating or grounding V_{DD} pin 38.
40	31,37	GND	ALL		Ground.
41	38,39	GND	ALL		Ground.
42	40	f _r	ALL	Input	Reference frequency input.
43	41	LD	ALL	Output	Lock detect and open drain logical inversion of CEXT. When the loop is in lock, LD is high impedance, otherwise LD is a logic low ("0").
44	42	Enh	Serial, Parallel	Input	Enhancement mode. When asserted low ("0"), enhancement register bits are functional.
N/A	34	NC	ALL		No connection.

Note 1: All V_{DD} pins are connected by diodes and must be supplied with the same positive voltage level. V_{DD} - f_p and V_{DD} - f_p are used to power the f_p and f_c outputs and can alternatively be left floating or connected to GND to disable the f_p and f_c outputs.

Note 2: All digital input pins have 70 $k\Omega$ pull-down resistors to ground.



Table 2. Absolute Maximum Ratings

Symbol	Parameter/Conditions	Min	Max	Units
V_{DD}	Supply voltage	-0.3	4.0	V
Vı	Voltage on any input	-0.3	V _{DD} + 0.3	V
l _l	DC into any input	-10	+10	mA
Ιο	DC into any output	-10	+10	mA
T_{stg}	Storage temperature range	-65	150	°C

Table 3. Operating Ratings

Symbol	Parameter/Conditions	Min	Max	Units
V_{DD}	Supply voltage	2.85	3.15	V
T _A	Operating ambient temperature range	-40	85	°C

Table 4. ESD Ratings

Symbol	Parameter/Conditions	Level	Units
V_{ESD}	ESD voltage (Human Body Model)	1000	V

Note 1: Periodically sampled, not 100% tested. Tested per MIL-STD-883, M3015 C2

Electrostatic Discharge (ESD) Precautions

When handling this UTSi device, observe the same precautions that you would use with other ESD-sensitive devices. Although this device contains circuitry to protect it from damage due to ESD, precautions should be taken to avoid exceeding the rating specified in Table 4.

Latch-Up Avoidance

Unlike conventional CMOS devices, UTSi CMOS devices are immune to latch-up.



Table 5. DC Characteristics

 V_{DD} = 3.0 V, -40° C < T_A < 85° C, unless otherwise specified

Symbol	Parameter	Conditions	Min	Тур	Max	Units
I _{DD}	Operational supply current;	V _{DD} = 2.85 to 3.15 V				
	Prescaler disabled			10		mA
	Prescaler enabled			19	26	mA
Digital Inputs:	All except f_r , R_0 , F_{in} , \overline{F}_{in}					
V_{IH}	High level input voltage	$V_{DD} = 2.85 \text{ to } 3.15 \text{ V}$	0.7 x V _{DD}			V
V _{IL}	Low level input voltage	$V_{DD} = 2.85 \text{ to } 3.15 \text{ V}$			$0.3 \times V_{DD}$	V
I _{IH}	High level input current	V _{IH} = V _{DD} = 3.15 V			+70	μΑ
I _{IL}	Low level input current	$V_{IL} = 0, V_{DD} = 3.15 V$	-1			μА
Reference Div	rider input: f _r	·				
I _{IHR}	High level input current	V _{IH} = V _{DD} = 3.15 V			+100	μА
I _{ILR}	Low level input current	$V_{IL} = 0, V_{DD} = 3.15 V$	-100			μА
R0 Input (Pull-	-up Resistor): R ₀	·				
I _{IHRO}	High level input current	V _{IH} = V _{DD} = 3.15 V			+5	μΑ
I _{ILRO}	Low level input current	V _{IL} = 0, V _{DD} = 3.15 V	-5			μА
Counter and p	phase detector outputs: f _c , f _p , PD_\overline{D}, PD_\overline{U}	•			•	
V _{OLD}	Output voltage LOW	I _{out} = 6 mA			0.4	V
V _{OHD}	Output voltage HIGH	I _{out} = -3 mA	V _{DD} - 0.4			V
Lock detect or	utputs: Cext, LD	·				
V _{OLC}	Output voltage LOW, Cext	I _{out} = 100 mA			0.4	V
V _{OHC}	Output voltage HIGH, Cext	I _{out} = -100 mA	V _{DD} - 0.4			V
V _{OLLD}	Output voltage LOW, LD	I _{out} = 6 mA			0.4	V



Table 6. AC Characteristics

 V_{DD} = 3.0 V, -40° C < T_A < 85° C, unless otherwise specified

Symbol	Parameter	Conditions	Min	Max	Units
Control Interfac	ce and Latches (see Figures 3, 4, 5)				•
f _{Clk}	Serial data clock frequency			10	MHz
t _{ClkH}	Serial clock HIGH time		30		ns
t _{ClkL}	Serial clock LOW time		30		ns
t _{DSU}	Sdata set-up time after Sclk rising edge, D[7:0] set-up time to M1_WR, M2_WR, A_WR, E_WR rising edge		10		ns
t _{DHLD}	Sdata hold time after Sclk rising edge, D[7:0] hold time to M1_WR, M2_WR, A_WR, E_WR rising edge		10		ns
t _{PW}	S_WR, M1_WR, M2_WR, A_WR, E_WR pulse width		30		ns
t _{CWR}	Sclk rising edge to S_WR rising edge. S_WR, M1_WR, M2_WR, A_WR falling edge to Hop_WR rising edge		30		ns
t _{CE}	Sclk falling edge to E_WR transition		30		ns
t _{WRC}	S_WR falling edge to Sclk rising edge. Hop_WR falling edge to S_WR, M1_WR, M2_WR, A_WR rising edge		30		ns
t _{EC}	E_WR transition to Sclk rising edge		30		ns
t_{MDO}	MSEL data out delay after Fin rising edge	C _L = 12 pf		8	ns
Main Divider (Ir	ncluding Prescaler)				
F _{in}	Operating frequency		500	3000	MHz
P_{Fin}	Input level range	External AC coupling	-5	5	dBm
Main Divider (P	Prescaler Bypassed)				
Fin	Operating frequency		50	300	MHz
P_{Fin}	Input level range	External AC coupling	-5	5	dBm
Reference Divid	der				
f _r	Operating frequency	(Note 1)	(Note 2)	100	MHz
P _{fr}	Reference input power	Single ended input	-2	10	dBm
V _{fr}	Input sensitivity	External AC coupling (Note 3)	0.5		V _{P-P}
Phase Detector	1				
f _c	Comparison frequency	(Note 1)		20	MHz

- Note 1: Parameter is guaranteed through characterization only and is not tested.
- **Note 2:** Running at low frequencies (< 10 MHz sinewave), the device will still be functional but may cause phase noise degradation. Inserting a low-noise amplifier to square up the edges is recommended at lower input frequencies.
- **Note 3:** CMOS logic levels may be used if DC coupled. For optimum phase noise performance, the reference input falling edge rate should be faster than 80mV/ns.

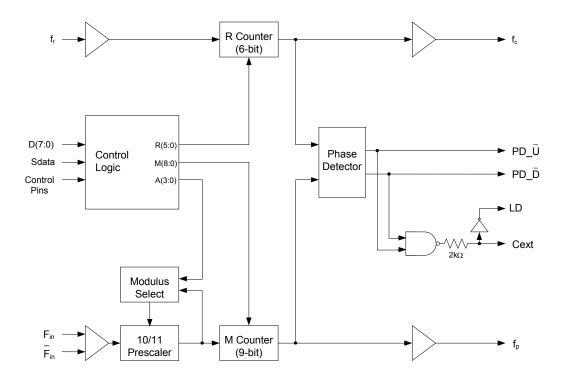


Functional Description

The PE3336 consists of a prescaler, counters, a phase detector and control logic. The dual modulus prescaler divides the VCO frequency by either 10 or 11, depending on the value of the modulus select. Counters "R" and "M" divide the reference and prescaler output, respectively, by integer values stored in a 20-bit register. An additional counter

("A") is used in the modulus select logic. The phase-frequency detector generates up and down frequency control signals. The control logic includes a selectable chip interface. Data can be written via serial bus, parallel bus, or hardwired direct to the pins. There are also various operational and test modes and lock detect.

Figure 3. Functional Block Diagram





Main Counter Chain

The main counter chain divides the RF input frequency, F_{in} , by an integer derived from the user defined values in the "M" and "A" counters. It is composed of the 10/11 dual modulus prescaler, modulus select logic, and 9-bit M counter. Setting $\overline{\text{Pre_en}}$ "low" enables the 10/11 prescaler. Setting $\overline{\text{Pre_en}}$ "high" allows F_{in} to bypass the prescaler and powers down the prescaler.

The output from the main counter chain, f_p , is related to the VCO frequency, F_{in} , by the following equation:

$$f_p = F_{in} / [10 \times (M + 1) + A]$$
 (1)
where $A \le M + 1, 1 \le M \le 511$

When the loop is locked, F_{in} is related to the reference frequency, f_r , by the following equation:

$$F_{in} = [10 \times (M+1) + A] \times (f_r / (R+1))$$
 (2) where $A \le M+1$, $1 \le M \le 511$

A consequence of the upper limit on A is that F_{in} must be greater than or equal to 90 x (f_r / (R+1)) to obtain contiguous channels. Programming the M Counter with the minimum value of "1" will result in a minimum M Counter divide ratio of "2".

When the prescaler is bypassed, the equation becomes:

$$F_{in} = (M + 1) \times (f_r / (R+1))$$
 (3)
where $1 \le M \le 511$

In Direct Interface Mode, main counter inputs M_7 and M_8 are internally forced low.

Reference Counter

The reference counter chain divides the reference frequency, f_r , down to the phase detector comparison frequency, f_c .

The output frequency of the 6-bit R Counter is related to the reference frequency by the following equation:

$$f_c = f_r / (R + 1)$$
 (4) where $0 \le R \le 63$

Note that programming R equal to "0" will pass the reference frequency, f_{r} , directly to the phase detector.

In Direct Interface Mode, R Counter inputs R_4 and R_5 are internally forced low ("0").

Register Programming

Parallel Interface Mode

<u>Parallel</u> Interface Mode is selected by setting the <u>Bmode</u> input "low" and the Smode input "low".

Parallel input data, D[7:0], are latched in a parallel fashion into one of three, 8-bit primary register sections on the rising edge of M1_WR, M2_WR, or A_WR per the mapping shown in Table 7 on page 10. The contents of the primary register are transferred into a secondary register on the rising edge of Hop_WR according to the timing diagram shown in Figure 4. Data are transferred to the counters as shown in Table 7 on page 10.

The secondary register acts as a buffer to allow rapid changes to the VCO frequency. This double buffering for "ping-pong" counter control is programmed via the FSELP input. When FSELP is "high", the primary register contents set the counter inputs. When FSELP is "low", the secondary register contents are utilized.

Parallel input data, D[7:0], are latched into the enhancement register on the rising edge of E_WR according to the timing diagram shown in Figure 4. This data provides control bits as shown in Table 8 on page 10 with bit functionality enabled by asserting the Enh input "low".

Serial Interface Mode

<u>Serial</u> Interface Mode is selected by setting the <u>Bmode</u> input "low" and the Smode input "high".

While the E_WR input is "low" and the S_WR input is "low", serial input data (Sdata input), B_0 to B_{19} , are clocked serially into the primary register on the rising edge of Sclk, MSB (B_0) first. The contents from the primary register are transferred into the secondary register on the rising edge of either S_WR or Hop_WR according to the timing diagram shown in Figures 4-5. Data are transferred to the counters as shown in Table 7 on page 10.

The double buffering provided by the primary and secondary registers allows for "ping-pong" counter control using the FSELS input. When FSELS is "high", the primary register contents set the counter inputs. When FSELS is "low", the secondary register contents are utilized.

While the E_WR input is "high" and the S_WR input is "low", serial input data (Sdata input), B_0 to B_7 , are clocked serially into the enhancement register on the rising edge of Sclk, MSB (B_0) first. The enhancement register is double buffered to prevent



inadvertent control changes during serial loading, with buffer capture of the serially entered data performed on the falling edge of E_WR according to the timing diagram shown in Figure 5. After the falling edge of E_WR, the data provide control bits as shown in Table 8 with bit functionality enabled by asserting the Enh input "low".

Direct Interface Mode

<u>Direct Interface Mode is selected by setting the Bmode input "high".</u>

Counter control bits are set directly at the pins as shown in Table 7. In Direct Interface Mode, main counter inputs M_7 and M_8 , and R Counter inputs R_4 and R_5 are internally forced low ("0").

Table 7. Primary Register Programming

Interface Mode	Enh	Bmode	Smode	R ₅	R ₄	M ₈	M ₇	Pre_en	M ₆	M ₅	M ₄	M ₃	M ₂	M ₁	M ₀	R ₃	R ₂	R ₁	R ₀	A ₃	A ₂	A ₁	A ₀
Parallel	1	0	0	M2_V	VR risir	ng edge	edge load M1_WR rising edge load					A_WR rising edge load											
				D_3	D_2	D_1	D_0	D_7	D_6	D_5	D_4	D_3	D_2	D_1	D_0	D_7	D_6	D_5	D_4	D_3	D_2	D_1	D_0
Serial*	1	0	1	B ₀	B ₁	B ₂	B ₃	B ₄	B ₅	B ₆	B ₇	B ₈	B ₉	B ₁₀	B ₁₁	B ₁₂	B ₁₃	B ₁₄	B ₁₅	B ₁₆	B ₁₇	B ₁₈	B ₁₉
Direct	1	1	Х	0	0	0	0	Pre_en	M ₆	M ₅	M ₄	M_3	M ₂	M ₁	M ₀	R ₃	R ₂	R ₁	R_0	A_3	A ₂	A ₁	A ₀

^{*}Serial data clocked serially on Sclk rising edge while E_WR "low" and captured in secondary register on S_WR rising edge.



(last in) LSB

Table 8. Enhancement Register Programming

Interface Mode	Enh	Bmode	Smode	Reserved	Reserved	Reserved	Power down	Counter load	MSEL output	Prescaler output	f_c , $f_p \overline{OE}$			
Parallel	0	Y	0		E_WR rising edge load									
Farallel	U	^	U	D_7	D_6	D ₅	D_4	D_3	D_2	D_1	D_0			
Serial*	0	Х	1	B ₀	B ₁	B ₂	B ₃	B ₄	B ₅	B ₆	B ₇			

^{*}Serial data clocked serially on Sclk rising edge while E_WR "high" and captured in the double buffer on E_WR falling edge.





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Figure 4. Parallel Interface Mode Timing Diagram

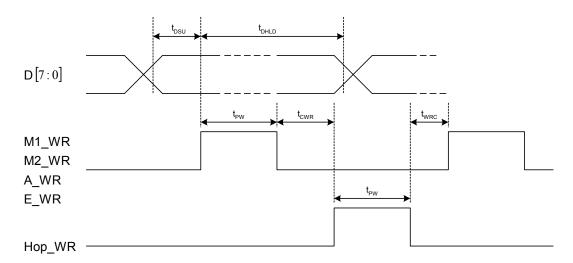
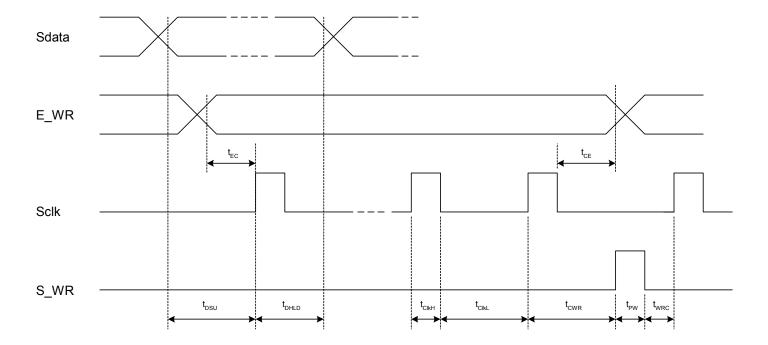


Figure 5. Serial Interface Mode Timing Diagram





Enhancement Register

The functions of the enhancement register bits are shown below with all bits active "high".

Table 9. Enhancement Register Bit Functionality

В	it Function	Description
Bit 0	Reserved**	
Bit 1	Reserved**	
Bit 2	Reserved**	
Bit 3	Power down	Power down of all functions except programming interface.
Bit 4	Counter load	Immediate and continuous load of counter programming as directed by the Bmode and Smode inputs.
Bit 5	MSEL output	Drives the internal dual modulus prescaler modulus select (MSEL) onto the Dout output.
Bit 6	Prescaler output	Drives the raw internal prescaler output onto the Dout output.
Bit 7	f_p , $f_c \overline{OE}$	f_p , f_c outputs disabled.

^{**} Program to 0

Phase Detector

The phase detector is triggered by rising edges from the main Counter (f_p) and the reference counter (f_c). It has two outputs, PD_ \overline{U} , and PD_ \overline{D} . If the divided VCO leads the divided reference in phase or frequency (f_p leads f_c), PD_ \overline{D} pulses "low". If the divided reference leads the divided VCO in phase or frequency (f_c leads f_p), PD_ \overline{U} pulses "low". The width of either pulse is directly proportional to phase offset between the two input signals, f_p and f_c .

The phase detector gain is equal to 2.7 V / 2 π , which numerically yields 0.43 V / radian.

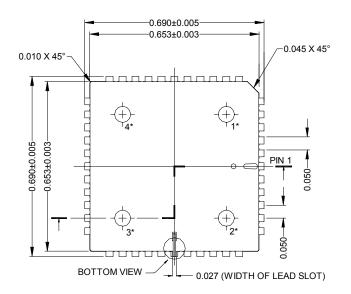
 $PD_\overline{U}$ and $PD_\overline{D}$ drive an active loop filter which controls the VCO tune voltage. $PD_\overline{U}$ pulses result in an increase in VCO frequency; $PD_\overline{D}$ pulses result in a decrease in VCO frequency (for a positive Kv VCO).

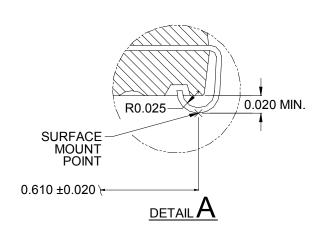
A lock detect output, LD is also provided, via the pin Cext. Cext is the logical "NAND" of PD_U and PD_D waveforms, which is driven through a series 2 kohm resistor. Connecting Cext to an external shunt capacitor provides low pass filtering of this signal. Cext also drives the input of an internal inverting comparator with an open drain output. Thus LD is an "AND" function of PD_U and PD_D.

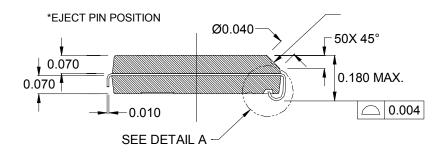


Figure 6. Package Drawing

44-lead PLCC





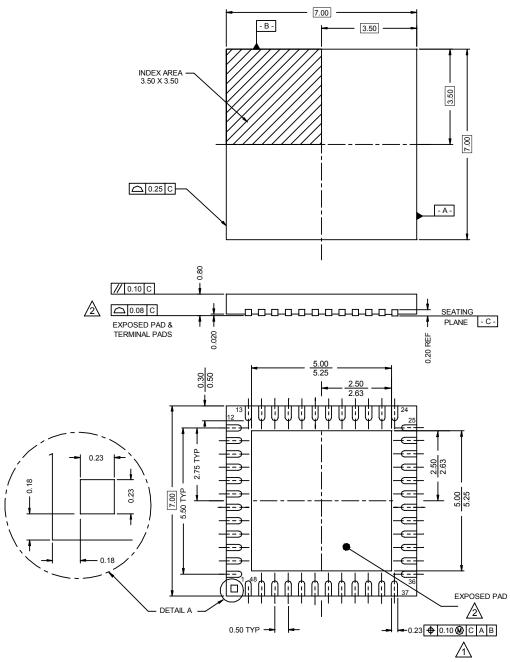


DIMENSIONS ARE IN INCHES TOLERANCES ARE ± 0.004



Figure 7. Package Drawing

48-lead MLPQ



- 1. DIMENSION APPLIES TO METALLIZED TERMINAL AND IS MEASURED BETWEEN 0.25 AND 0.30 FROM TERMINAL TIP.
- 2. COPLANARITY APPLIES TO THE EXPOSED HEAT SINK SLUG AS WELL AS THE TERMINALS.



Table 10. Ordering Information

Order Code	Part Marking	Description	Package	Shipping Method	Product Status
3336-21	PE3336		44-lead PLCC	26 units / Tube	Production
3336-22	PE3336		44-lead PLCC	500 units / T&R	Production
3336-23	PE3336		48-lead MLPQ	52 units / Tube	Evaluation Samples
3336-24	PE3336		48-lead MLPQ	4000 units / T&R	Evaluation Samples
3336-00	PE3336EK	PLCC Evaluation Board with Software	44-lead PLCC	1 / Box	Available
3336-01	PE3336EK	MLPQ Evaluation Board with Software	48-lead MLPQ	1 / Box	Available



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Data Sheet Identification

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Preliminary Specification

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Product Specification

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